## NSN 5961-00-104-0115

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-104-0115 **Inclosure Material:** Glass **Overall Length:** Between 0.245 inches and 0.280 inches **Overall Height:** Between 0.032 inches and 0.059 inches **Overall Width:** 0.155 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage, dc all transistor and -60.0 collector to emitter voltage, dc all transistor and -5.0 emitter to base voltage, dc all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig: A110a0